

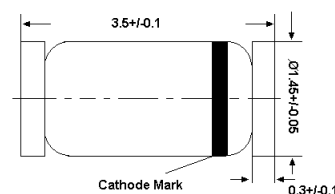
LL-34 Plastic-Encapsulate Diodes

FAST SWITCHING DIODE

Features:

- Low Reverse Current
- Surface Mount Package Ideally Suited for Automatic Insertion
- Fast Switching Speed
- For General Purpose Switching Applications

LL-34



Glass case MiniMELF
 Dimensions in mm

Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

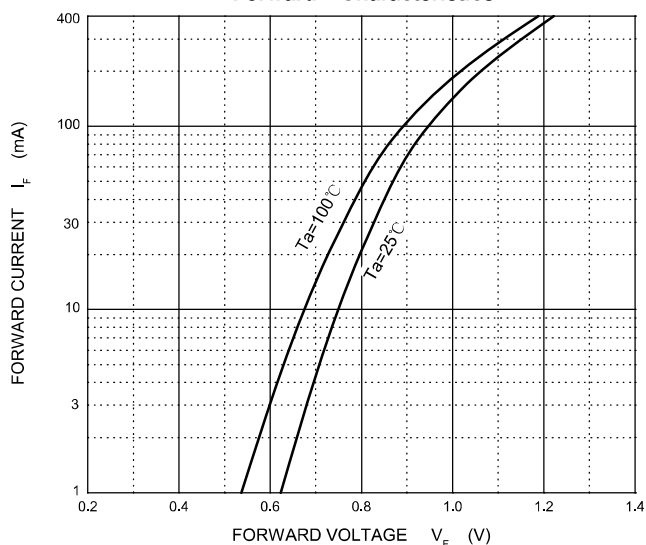
Parameter	Symbol	RLS243	RLS244	RLS245	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	120	200	250	V
Peak Repetitive Peak Reverse Voltage	V_{RRM}				
Working Peak Reverse Voltage	V_{RWM}	100	150	250	V
DC Blocking Voltage	V_R				
RMS Reverse Voltage	$V_{R(RMS)}$	84	105	220	V
Forward Continuous Current	I_{FM}		800		mA
Average Rectified Output Current	I_O		200		mA
Peak Forward Surge Current @t=1.0ms @t =1.0s	I_{FSM}		2.5 0.5		A
Repetitive Peak Forward Current	I_{FRM}		625		mA
Power Dissipation	P_d		500		mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$		250		°C/W
Storage Temperature	T_{STG}		-55~+150		°C

Electrical Ratings @Ta=25°C

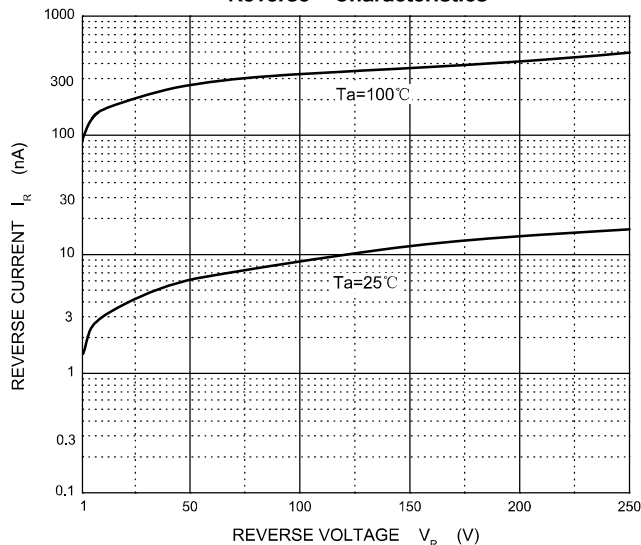
Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V_{F1}			1.0	V	$I_F=0.1A$
	V_{F2}			1.25		$I_F=0.2A$
Reverse current	I_R			0.1	μA	$V_R=100V$
				0.1		$V_R=150V$
				0.1		$V_R=200V$
Capacitance between terminals	C_T			5	pF	$V_R=0V, f=1MHz$
Reverse recovery time	t_{rr}			75	ns	$I_F=I_R=30mA$ $I_{rr}=0.1 \times I_R, R_L=100\Omega$

Typical Characteristics

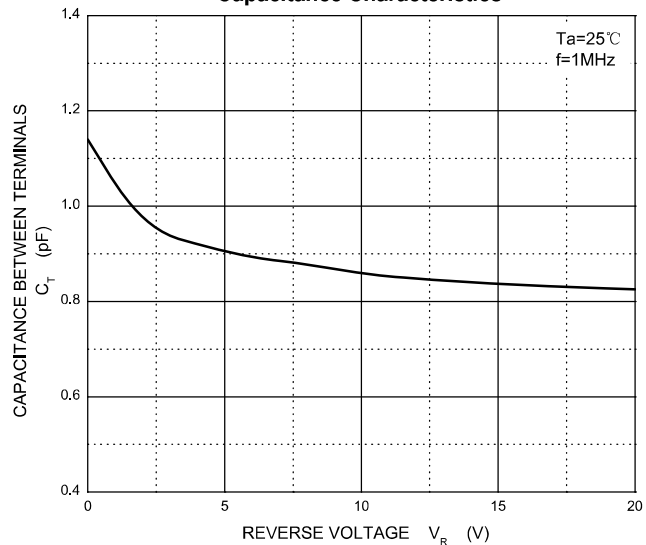
Forward Characteristics



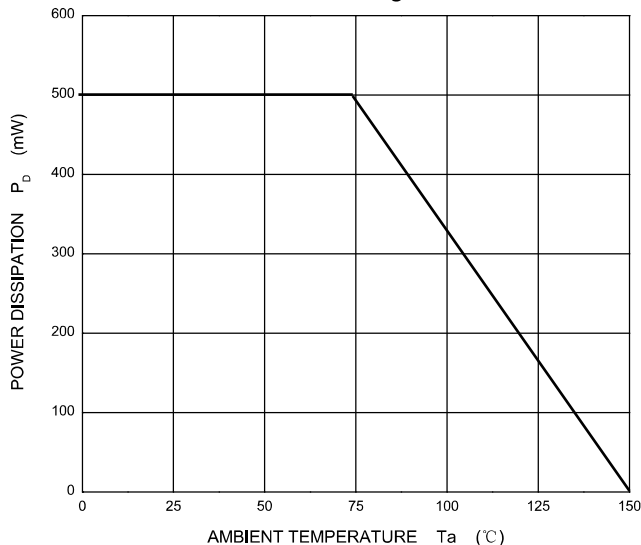
Reverse Characteristics



Capacitance Characteristics



Power Derating Curve



Packaging Specifications for Surface Mounted Glass & Mold Diodes

1. The method of packaging and dimension are shown as below figure. (Dimension in mm)

